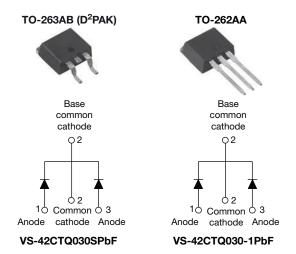
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High Performance Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY TO-263AB (D²PAK), TO-262AA Package 2 x 20 A I_{F(AV)} 30 V V_R 0.38 V V_F at I_F I_{RM} max. 183 mA at 125 °C T_{.1} max. 150 °C **Diode variation** Common cathode 13 E_{AS}

FEATURES

- 150 °C T_J operation
- · Center tap configuration
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long
 term reliability
- RoHS COMPLIANT HALOGEN FREE
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	40	A			
V _{RRM}		30	V			
I _{FSM}	t _p = 5 μs sine	1100	A			
V _F	20 A_{pk} , T_J = 125 °C (per leg)	0.38	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-42CTQ030SPbF VS-42CTQ030-1PbF	UNITS
Maximum DC reverse voltage	V _R	30	V
Maximum working peak reverse voltage	V _{RWM}	30	v

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average forward	per leg	1	50 % duty cycle at T_{C} = 121 °C	rootangular wayoform	20		
current, see fig. 5	per device	I _{F(AV)}	50% duty cycle at $T_C = 121\%$, rectangular wavelonn	40		
Maximum peak one cycle non-	aximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	1100	A	
surge current per leg, see fig. 7		IFSM	10 ms sine or 6 ms rect. pulse	condition and with rated V _{BBM} applied	360		
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 2.90 mH		13	mJ	
Repetitive avalanche current pe	er leg	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim		3	А	

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VS-42CTQ030SPbF, VS-42CTQ030-1PbF

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		20 A	T.I = 25 °C	0.48	
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	1j=25 C	0.57 0.38	v
See fig. 1	V FM (")	20 A	T.I = 125 °C		v
		40 A	$I_{\rm J} = 125$ C	0.51	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	$T_J = 25 \text{ °C}$		3	mA
See fig. 2	IRM \''	T _J = 125 °C	V _R = Rated V _R	183	IIIA
Threshold Voltage	V _{F(TO)}			0.22	V
Forward slope resistance	r _t	T _J =T _J maximum		6.76	mΩ
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal rang	ge 100 kHz to 1 MHz), 25 °C	2840	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 m	m from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and stor temperature range	age	T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance junction to case per leg	ce,	P				
Maximum thermal resistance, junction to case per package		R _{thJC}	JC DC operation	1.0	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased 0.50]	
Approvimate weight				2	g	
Approximate weight				0.07	oz.	
minimum				6 (5)	kgf ⋅ cm	
Mounting torque	maximum			12 (10)	(lbf ⋅ in)	
Marking davias			Case style TO-263AB (D ² PAK)	42CTC	030S	
Marking device			Case style TO-262AA	42CTQ	030-1	



VS-42CTQ030SPbF, VS-42CTQ030-1PbF

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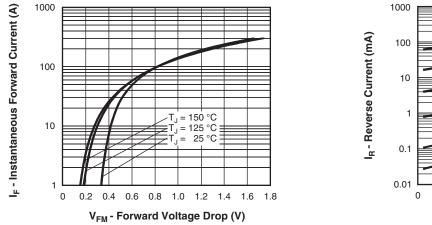
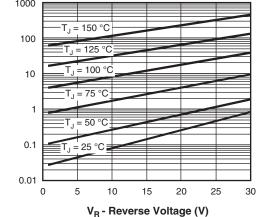
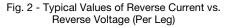


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





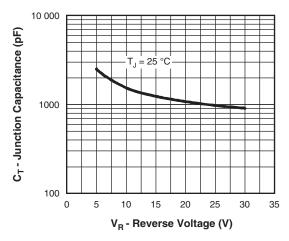
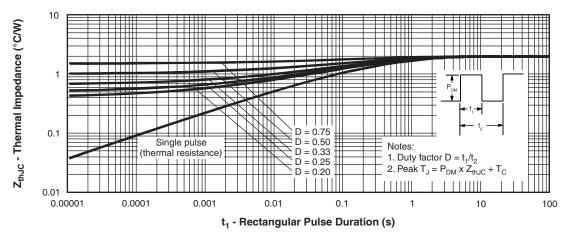


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)



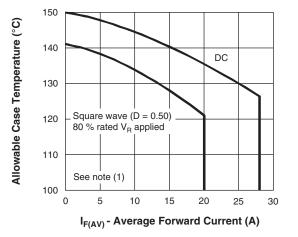


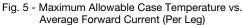
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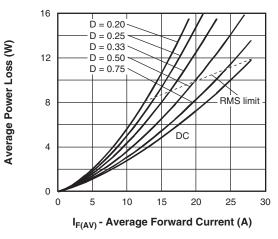


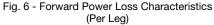
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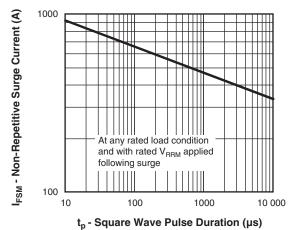
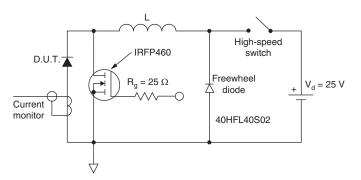


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)





Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{10} \ \mathsf{V} \end{array}$

Revision: 08-Dec-14

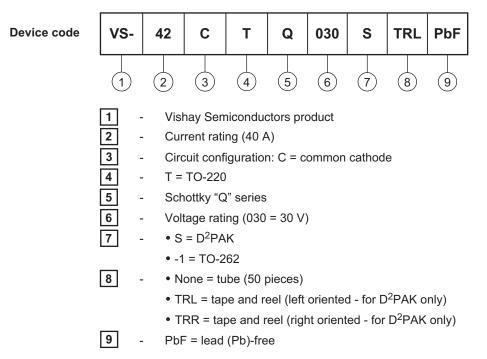
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ORDERING INFORMATION TABLE

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ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-42CTQ030SPBF	50	1000	Antistatic plastic tubes				
VS-42CTQ030STRRPBF	800	800	13" diameter plastic tape and reel				
VS-42CTQ030STRLPBF	800	800	13" diameter plastic tape and reel				
VS-42CTQ030-1PBF	50	1000	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS						
Dimonsions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046				
Dimensions	TO-262AA	www.vishay.com/doc?95419				
Part marking information		www.vishay.com/doc?95008				
Packaging information		www.vishay.com/doc?95032				

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

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SYMBOL	MILLIM	IETERS	INC	HES	NOTES		SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

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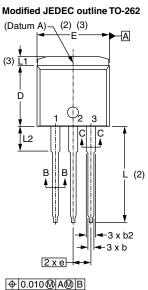


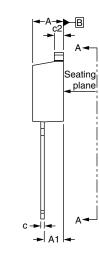
Outline Dimensions

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TO-262

DIMENSIONS in millimeters and inches

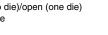


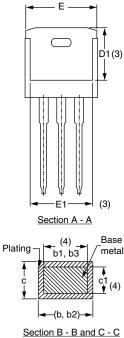


Lead assignments



Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode





Scale: None

SYMBOL	MILLIM	ETERS	INC	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.10	0 BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

Revision: 04-Oct-10

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

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